MPEG Clock Generator with VCXO
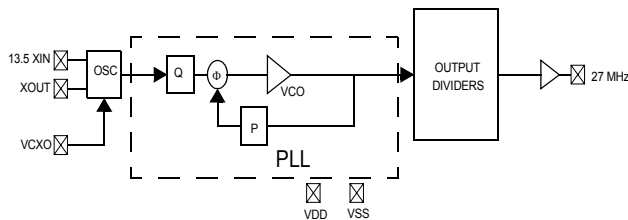
Features

- **Integrated phase-locked loop (PLL)**
- **Low-jitter, high-accuracy outputs**
- **VCXO with analog adjust**
- **3.3V operation**
- **Compatible with MK3727 (–5, –6)**
- **Application compatibility for a wide variety of designs**
- **Enables design compatibility**
- **Lower drive strength settings (CY241V08A–06)**

Benefits

- Digital VCXO control
- Electromagnetic interference (EMI) reduction for standards compliance
- Second source for existing designs
- Highest-performance PLL tailored for multimedia applications
- Meets critical timing requirements in complex system designs

CY241V08A–05,–06 Logic Block Diagram

Pin Configurations

CY241V08A–05,–06
8-pin SOIC
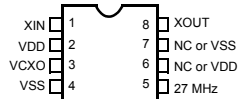
Part Number	Outputs	Input Frequency Range	Output Frequencies	VCXO Control Curve	Other Features
CY241V08A–05	1	13.5-MHz pullable crystal input per Cypress specification	1 copy of 27 MHz	non-linear	Compatible with MK3727A non linear VCXO control
CY241V08A–06	1	13.5-MHz pullable crystal input per Cypress specification	1 copy of 27 MHz	non-linear	Same as CY241V08A–05 except lower drive strength

Pin Description

Name	Pin Number	Description
XIN	1	**Reference crystal input**
VDD	2	**Voltage supply**
VCXO	3	**Input analog control for VCXO**
VSS	4	**Ground**
27 MHz	5	**27-MHz clock output**
NC/VDD	6	**No connect or voltage supply**
NC/VSS	7	**No connect or ground**
XOUT	8	**Reference crystal output**

Absolute Maximum Conditions

Supply Voltage (V_{DD}) ....–0.5 to +7.0V

DC Input Voltage..................................... –0.5V to V_{DD} + 0.5

Storage Temperature (Non-condensing).....–55°C to +125°C

Junction Temperature .... –40°C to +125°C

Data Retention @ Tj = 125°C ....> 10 years

Package Power Dissipation...................................... 350 mW

ESD (Human Body Model) MIL-STD-883................ > 2000V

(Above which the useful life may be impaired. For user guidelines, not tested.)

Pullable Crystal Specifications[1]

Parameter	Description	Comments	Min.	Typ.	Max.	Unit
F_{NOM}	Nominal crystal frequency	Parallel resonance, fundamental mode, AT cut	–	13.5	–	MHz
C_{LNOM}	Nominal load capacitance		–	14	–	pF
R_1	Equivalent series resistance (ESR)	Fundamental mode	–	–	25	Ω
R_3/R_1	Ratio of third overtone mode ESR to fundamental mode ESR	Ratio used because typical R_1 values are much less than the maximum spec	3	–	–	–
DL	Crystal drive level	No external series resistor assumed	150	–	–	μW
F_{3SEPHI}	Third overtone separation from $3*F_{NOM}$	High side	300	–	–	ppm
F_{3SEPLO}	Third overtone separation from $3*F_{NOM}$	Low side	–	–	–150	ppm
C_0	Crystal shunt capacitance		–	–	7	pF
C_0/C_1	Ratio of shunt to motional capacitance		180	–	250	–
C_1	Crystal motional capacitance		14.4	18	21.6	fF

Recommended Operating Conditions

| Parameter	Description	Min.	Typ.	Max.	Unit
VDD	Operating Voltage	3.135	3.3	3.465	V
T_A	Ambient Temperature	0	–	70	°C
C_{LOAD}	Max. Load Capacitance	–	–	15	pF
t_{PU}	Power-up time for all VDD pins to reach minimum specified voltage (power ramps must be monotonic)	0.05	–	500	ms

DC Electrical Specifications

Parameter	Name	Description	Min.	Typ.	Max.	Unit
I_{OH}	Output HIGH Current	V_{OH} = V_{DD} – 0.5V, V_{DD} = 3.3V	12	24	–	mA
I_{OL}	Output LOW Current	V_{OL} = 0.5V, V_{DD} = 3.3V	12	24	–	mA
C_{IN}	Input Capacitance	Except XIN, XOUT pins	–	–	7	pF
V_{VCXO}	VCXO Input Range		0	–	V_{DD}	V
$f_{\Delta XO}$[2]	VCXO Pullability Range	Low Side	–	–	–75	ppm
		High Side	75	–	–	ppm
I_{VDD}	Supply Current		–	30	35	mA

Notes:
1. Crystals that meet this specification includes: Ecliptek ECX-5788-13.500M,Siward XTL001050A-13.5-14-400, Raltron A-13.500-14-CL,PDI HA13500XFSA14XC.
2. –75/+75 ppm assumes 2.5 pF of additional board level load capacitance. This range will be shifted down with more board capacitance or shifted up with less board capacitance.

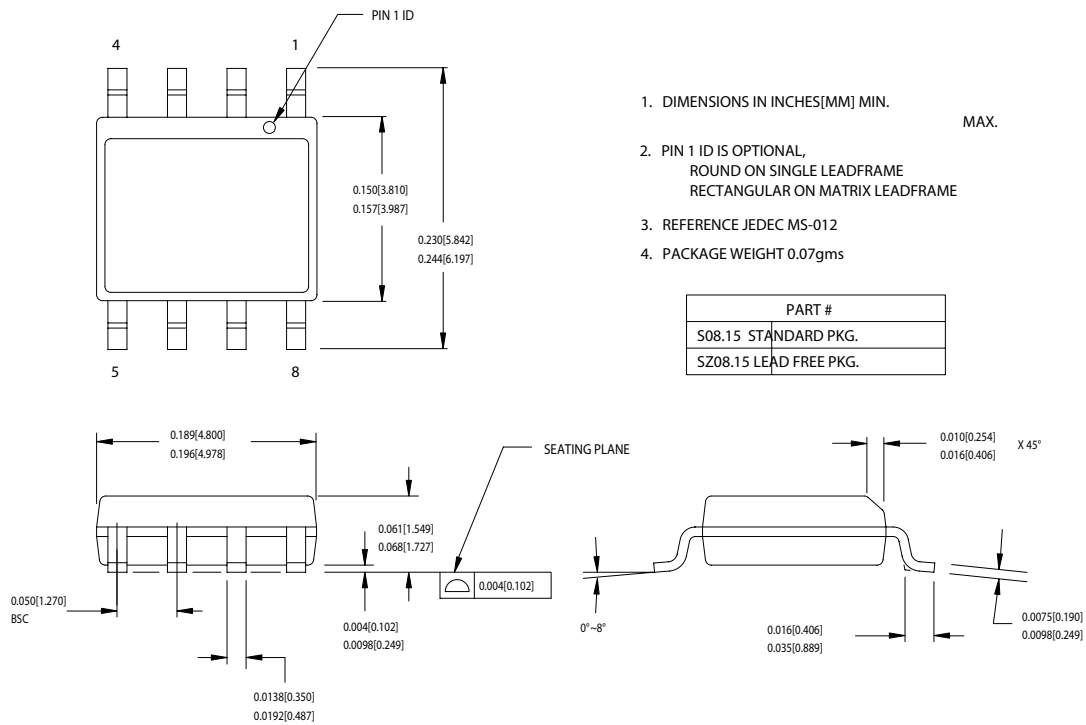## AC Electrical Specifications (V_{DD} = 3.3V) [3]

Parameter[3]	Name	Description	Min.	Typ.	Max.	Unit
DC	Output Duty Cycle	Duty Cycle is defined in *Figure 1*, 50% of V_{DD}	45	50	55	%
ER_{OR}	Rising Edge Rate –05	Output Clock Edge Rate, Measured from 20% to 80% of V_{DD}, CLOAD = 15 pF See *Figure 2*.	0.8	1.4	–	V/ns
ER_{OF}	Falling Edge Rate –05	Output Clock Edge Rate, Measured from 80% to 20% of V_{DD}, CLOAD = 15 pF See *Figure 2*.	0.8	1.4	–	V/ns
ER_{OR}	Rising Edge Rate –06	Output Clock Edge Rate, Measured from 20% to 80% of V_{DD}, CLOAD = 15 pF See *Figure 2*.	0.7	1.1	–	V/ns
ER_{OF}	Falling Edge Rate –06	Output Clock Edge Rate, Measured from 80% to 20% of V_{DD}, CLOAD = 15 pF See *Figure 2*.	0.7	1.1	–	V/ns
t_9	Clock Jitter	Peak-to-peak period jitter	–	–	100	ps
t_{10}	PLL Lock Time		–	–	3	ms

Test and Measurement Set-up
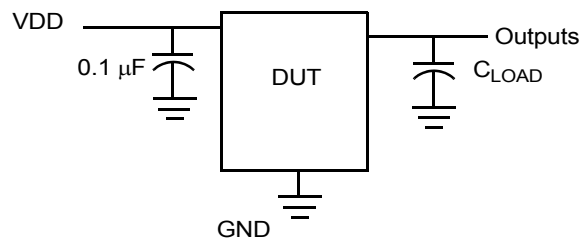
Voltage and Timing Definitions
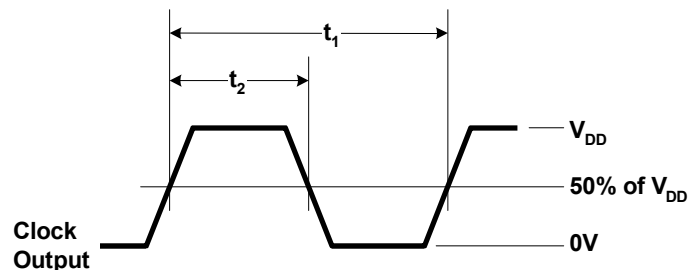
Figure 1. Duty Cycle Definition
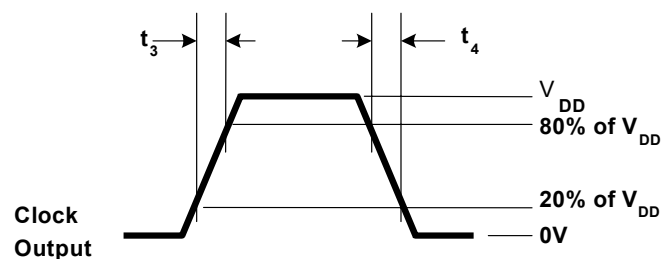
Figure 2. ER = (0.6 x V_{DD}) /t3, EF = (0.6 x V_{DD}) /t4

Note:
3. Not 100% tested.

Ordering Information

Ordering Code	Package Name	Package Type	Operating Range	Operating Voltage	Features
CY241V08ASC–05,06	S8	8-pin SOIC	Commercial	3.3V	Linear VCXO control curve
CY241V08ASC–05,06T	S8	8-pin SOIC - Tape and Reel	Commercial	3.3V	Linear VCXO control curve

Package Drawing and Dimensions

8-lead (150-Mil) SOIC S8

1. DIMENSIONS IN INCHES[MM] MIN.

   MAX.

2. PIN 1 ID IS OPTIONAL,
   ROUND ON SINGLE LEADFRAME
   RECTANGULAR ON MATRIX LEADFRAME

3. REFERENCE JEDEC MS-012

4. PACKAGE WEIGHT 0.07gms

PART #
S08.15 STANDARD PKG.
SZ08.15 LEAD FREE PKG.

51-85066-*C

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Document History Page

Document Title: CY241V08A-05,06 MPEG Clock Generator with VCXO Document Number: 38-07670				
REV.	**ECN NO.**	**Issue Date**	**Orig. of Change**	**Description of Change**
**	214066	See ECN	RGL	New Data Sheet